SDLS108 - APRIL 1985 - REVISED MARCH 1988

- Package Options Include Plastic "Small Outline" Packages, Ceramic Chip Carriers and Flat Packages in Addition to Plastic and Ceramic DIPs
- Dependable Texas Instruments Quality and Reliability

description

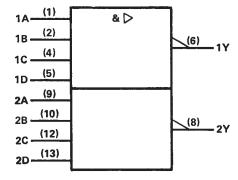
These devices contain two independent 4-input NAND buffer gates.

The SN5440, SN54LS40, and SN54S40 are characterized for operation over the full military temperature range of $-55\,^{\circ}\text{C}$ to $125\,^{\circ}\text{C}$. The SN7440, SN74LS40, and SN74S40 are characterized for operation from $0\,^{\circ}\text{C}$ to $70\,^{\circ}\text{C}$.

FUNCTION TABLE (each gate)

	INP	UTS		OUTPUT
A	В	С	D	Y
Н	Н	н	Н	L
L	X	X	Х	н
Х	L	X	Х	н
Х	Х	L	Х	Н
x	Х	X	L	Н

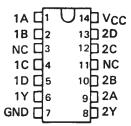
logic symbol†



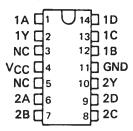
[†]This symbol is in accordance with ANSI/IEEE Std. 91-1984 and IEC Publication 617-12.

Pin numbers shown are for D, J, N, and W packages.

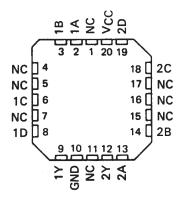
SN5440 . . . J PACKAGE SN54LS40, SN54S40 . . . J OR W PACKAGE SN7440 . . . N PACKAGE SN74LS40, SN74S40 . . . D OR N PACKAGE (TOP VIEW)



SN5440 . . . W PACKAGE (TOP VIEW)

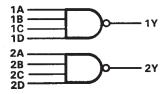


SN54LS40, SN54S40 . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

logic diagram



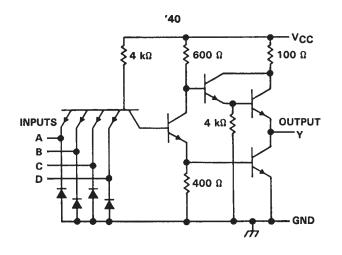
positive logic

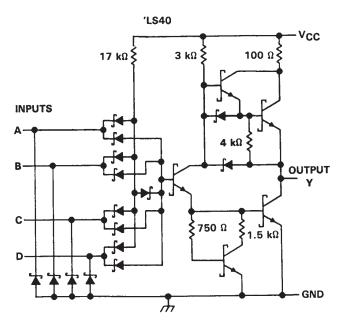
 $Y = \overline{A \cdot B \cdot C \cdot D}$ or $Y = \overline{A} + \overline{B} + \overline{C} + \overline{D}$

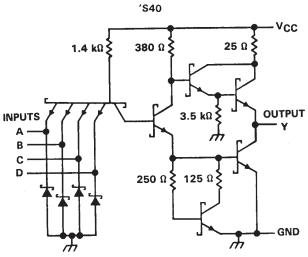


SDLS108 - APRIL 1985 - REVISED MARCH 1988

schematics (each gate)







Resistor values shown are nominal.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, VCC (see Note 1)	1
nput voltage: '40, 'S40	,
'LS40 7 V	1
Operating free-air temperature range: SN54'	,
SN74'	,
Storage temperature range65°C to 150°C	

NOTE 1: Voltage values are with respect to network ground terminal.



SDLS108 – APRIL 1985 – REVISED MARCH 1988

recommended operating conditions

			SN5440)		SN7440)	UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	ONLL
Vcc	Supply voltage	4.5	5	5.5	4.75	5	5.25	٧
VIH	High-level input voltage	2			2			V
VIL	Low-level input voltage			0.8			0.8	V
ЮН	High-level output current			- 1.2			- 1.2	mA
loL	Low-level output current			48			48	mA
TA	Operating free-air temperature	- 55		125	0		70	°c

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDIT	uone t		SN5440)	[SN7440)	UNIT
PARAMETER		LEST CONDIT	IONS I	MIN	TYP‡	MAX	MIN	TYP‡	MAX	UNIT
VIK	V _{CC} = MIN,	I _I = - 12 mA				- 1.5			- 1.5	V
Voн	V _{CC} = MIN,	V ₁ L = 0.8 V,	I _{OH} = - 1.2 mA	2.4	3.3		2.4	3.3		٧
VOL	V _{CC} = MIN,	V _{IH} = 2 V,	IOL = 48 mA		0.2	0.4		0.2	0.4	V
Τį	V _{CC} = MAX,	V _I = 5.5 V				1			1	mA
ЧН	V _{CC} = MAX,	V ₁ = 2.4 V				40			40	μА
IL	V _{CC} = MAX,	V _I = 0.4 V				– 1.6			- 1.6	mA
IOS§	V _{CC} = MAX			- 20		– 70	- 18		– 70	mA
ГССН	V _{CC} = MAX,	V ₁ = 0			4	8		4	8	mA
ICCL	V _{CC} = MAX,	V ₁ = 4.5 V			17	27		17	27	mA

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

switching characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$ (see note 2)

PARAMETER	FROM	TO	TEST CON	DITIONS	MIN	TYP	MAX	UNIT
PARAMETER	(INPUT)	(OUTPUT)	IEST CON	DITIONS	IVITIV	ITE	WAA	UNIT
^t PLH	A 01/	~	$R_1 = 133 \Omega_r$	C. = 15 oF		13	22	ns
tPHL	Any	ľ	n[= 133 12,	C _L = 15 pF		8	15	ns

NOTE 2: Load circuits and voltage waveforms are shown in Section 1.



[‡] All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$. § Not more than one output should be shorted at a time, and the duration of the short circuit should not exceed 100 milliseconds.

SDLS108 - APRIL 1985 - REVISED MARCH 1988

recommended operating conditions

	S	N54LS	40	S	N74LS4	10	UNIT
	MIN	NOM	MAX	MIN	NOM	MAX	ONT
V _{CC} Supply voltage	4.5	5	5.5	4.75	5	5.25	V
V _{IH} High-level input voltage	2			2			٧
VIL Low-level input voltage			0.7			0 8	
IOH High-level output current		******	- 1.2			- 1.2	mA
IOL Low-level output current			12			24	mA
TA Operating free-air temperature	- 55		125	0		70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

				S	N54LS4	10	S	N74LS4	10	UNIT
PARAMETER		TEST CONDIT	IONS I	MIN	TYP‡	MAX	MIN	TYP‡	MAX	ONT
VIK	V _{CC} = MIN,	I _I = - 18 mA				- 1.5			– 1.5	٧
VoH	V _{CC} = MIN,	V _{IL} = MAX,	I _{OH} = - 1.2 mA	2.5	3.4		2.7	3.4		٧
V	V _{CC} = MIN,	V _{IH} = 2 V,	I _{OL} = 12 mA		0.25	0.4		0.25	0.4	v
VOL	V _{CC} = MIN,	V _{IH} = 2 V,	IOL = 24 mA					0.35	0.5	
l ₁	V _{CC} = MAX,	V _I = 7 V				0.1			0.1	mA
ЧН	V _{CC} = MAX,	V _I = 2.7 V				20			20	μΑ
IIL	V _{CC} = MAX,	V _I = 0.4 V				- 0.4			- 0.4	mA
IOS §	V _{CC} = MAX			- 30		– 130	– 30		– 130	mA
Іссн	V _{CC} = MAX,	V = 0			0.45	1		0.45	11	mA
ICCL	V _{CC} = MAX,	V ₁ = 4.5 V			3	6		3	6	mA

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

switching characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$ (see note 2)

PARAN	METER	FROM (INPUT)	TO (OUTPUT)	TEST CON	DITIONS	MIN	TYP	MAX	UNIT
tpLi	Н	A	V	D. = 667 O	C. = 45 pE		12	24	ns
tPHI	1	Any	1	$R_{L} = 667 \Omega$,	C _L = 45 pF		12	24	ns

NOTE 2: Load circuits and voltage waveforms are shown in Section 1.



[‡] All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ} \text{ C}$. § Not more than one output should be shorted at a time, and the duration of the short circuit should not exceed one second.

SDLS108 – APRIL 1985 – REVISED MARCH 1988

recommended operating conditions

			SN54S4	0		SN74S4	0	UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	UNIT
Vcc	Supply voltage	4.5	5	5.5	4.75	5	5.25	٧
VIH	High-level input voltage	2			2			٧
VIL	Low-level input voltage			0.8			0.8	V
Іон	High-level output current			- 3			- 3	mA
loL	Low-level output current			60			60	mA
TA	Operating free-air temperature	- 55		125	0		70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

242445752		TEAT CONO.	210N0 †		N54S40)		SN74S40)	UNIT
PARAMETER		TEST CONDIT	IONS I	MIN	TYP ‡	MAX	MIN	TYP‡	MAX	UNIT
VIK	V _{CC} = MIN,	I _I = - 18 mA				- 1.2			- 1.2	٧
Voн	V _{CC} = MIN,	V _{1L} = 0.8 V,	I _{OH} = - 3 mA	2.5	3.4		2.7	3.4		V
VOL	V _{CC} = MIN,	V _{IH} = 2 V,	I _{OL} = 60 mA			0.5			0.5	V
i ₁	V _{CC} = MAX,	V _I = 5.5 V				1			1	mA
ΊΗ	V _{CC} = MAX,	V _I = 2.7 V				0.1			0.1	mA
^J 1L	V _{CC} = MAX,	V _I = 0.5 V				- 4			- 4	mA
108\$	V _{CC} = MAX			- 50		– 225	– 50		- 225	mA
1ссн	V _{CC} = MAX,	V _I = 0			10	18		10	18	mA
ICCL	V _{CC} = MAX,	V ₁ = 4.5 V			25	44		25	44	mA

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

switching characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$ (see note 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST COM	IDITIONS	MIN TYP	MAX	UNIT
t _{PLH}			R _L = 93 Ω,	C _L = 50 pF	4	6.5	ns
^t PHL	A 214		u [- 30 11,	C[- 50 pr	4	6.5	ns
^t PLH	Any	l ' [R _L = 93 Ω,	C _I = 150 pF	6		ns
^t PHL			HE = 50 46,	CL 130 pr	6		ns

NOTE 2: Load circuits and voltage waveforms are shown in Section 1.



[‡] All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

[§] Not more than one output should be shorted at a time, and the duration of the short-circuit should not exceed 100 milliseconds.

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